

View Online at <https://aerobasegroup.com/nsn/5961-01-338-0675>

**Inclosure Material:**

Glass all semiconductor device diode

**Overall Length:**

0.150 inches all semiconductor device diode and 0.170 inches all semiconductor device diode

**Terminal Length:**

1.000 inches all semiconductor device diode and 1.500 inches all semiconductor device diode

**Overall Diameter:**

0.068 inches all semiconductor device diode and 0.076 inches all semiconductor device diode

**End Application:**

5895-01-177-0791 receiver-transmitter

**Internal Configuration:**

Junction contact all semiconductor device diode

**Internal Junction Configuration:**

Pn all semiconductor device diode

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

4 semiconductor device diode

**Mounting Method:**

Terminal all semiconductor device diode

**Field Force Effect Type:**

Electrostatic charge

**Features Provided:**

Burn in and electrostatic sensitive

**Semiconductor Material:**

Silicon all semiconductor device diode

**Voltage Rating In Volts Per Characteristic:**

50.0 working peak reverse voltage all semiconductor device diode

**Power Rating Per Characteristic:**

250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction all semiconductor device diode

**Test Data Document:**

80063-a3006760 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:**

2 uninsulated wire lead all semiconductor device diode

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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